

## +/-15kV, ESD-Protected, +5V Powered, RS-232 Transmitters/Receivers

The HIN202E-HIN241E family of RS-232 transmitters/receivers interface circuits meet all EIA high-speed RS-232E and V.28 specifications, and are particularly suited for those applications where  $\pm 12V$  is not available. A redesigned transmitter circuit improves data rate and slew rate, which makes this suitable for ISDN and high speed modems. The transmitter outputs and receiver inputs are protected to  $\pm 15kV$  ESD (Electrostatic Discharge). They require a single +5V power supply and feature onboard charge pump voltage converters which generate +10V and -10V supplies from the 5V supply. The family of devices offers a wide variety of high-speed RS-232 transmitter/receiver combinations to accommodate various applications (see Selection Table).

The HIN206E, HIN211E, HIN213E, HIN236E, and HIN241E feature a low power shutdown mode to conserve energy in battery powered applications. In addition, the HIN213E provides two active receivers in shutdown mode allowing for easy "wakeup" capability.

The drivers feature true TTL/CMOS input compatibility, slew rate-limited output, and  $300\Omega$  power-off source impedance. The receivers can handle up to  $\pm 30V$  input, and have a  $3k\Omega$  to  $7k\Omega$  input impedance. The receivers also feature hysteresis to greatly improve noise rejection.

## Applications

- Any System Requiring High-Speed RS-232 Communications Port
  - Computer - Portable, Mainframe, Laptop
  - Peripheral - Printers and Terminals
  - Instrumentation, UPS
  - Modems, ISDN Terminal Adaptors

## Selection Table

PART NUMBER	POWER SUPPLY VOLTAGE	NUMBER OF RS-232 DRIVERS	NUMBER OF RS-232 RECEIVERS	NUMBER OF 0.1 $\mu$ F EXTERNAL CAPACITORS	LOW POWER SHUTDOWN/TTL THREE-STATE	NUMBER OF RECEIVERS ACTIVE IN SHUTDOWN
HIN202E	+5V	2	2	4 Capacitors	NO/NO	0
HIN206E	+5V	4	3	4 Capacitors	YES/YES	0
HIN207E	+5V	5	3	4 Capacitors	NO/NO	0
HIN208E	+5V	4	4	4 Capacitors	NO/NO	0
HIN211E	+5V	4	5	4 Capacitors	YES/YES	0
HIN213E	+5V	4	5	4 Capacitors	YES/YES	2
HIN232E	+5V	2	2	4 Capacitors	NO/NO	0
HIN236E	+5V	4	3	4 Capacitors	YES/YES	0
HIN237E	+5V	5	3	4 Capacitors	NO/NO	0
HIN238E	+5V	4	4	4 Capacitors	NO/NO	0
HIN241E	+5V	4	5	4 Capacitors	YES/YES	0

## Features

- High Speed ISDN Compatible ..... 230kbits/s
- ESD Protection for RS-232 I/O Pins to  $\pm 15kV$  (IEC1000)
- Meets All RS-232E and V.28 Specifications
- Requires Only 0.1 $\mu$ F or Greater External Capacitors
- Two Receivers Active in Shutdown Mode (HIN213E)
- Requires Only Single +5V Power Supply
- Onboard Voltage Doubler/Inverter
- Low Power Consumption (Typ) ..... 5mA
- Low Power Shutdown Function (Typ) ..... 1 $\mu$ A
- Three-State TTL/CMOS Receiver Outputs
- Multiple Drivers
  - $\pm 10V$  Output Swing for +5V Input
  - $300\Omega$  Power-Off Source Impedance
  - Output Current Limiting
  - TTL/CMOS Compatible
- Multiple Receivers
  - $\pm 30V$  Input Voltage Range
  - $3k\Omega$  to  $7k\Omega$  Input Impedance
  - 0.5V Hysteresis to Improve Noise Rejection

**Ordering Information**

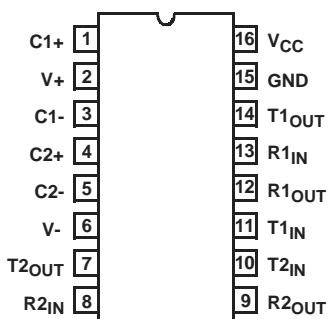
PART NO.	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
HIN202ECB	0 to 70	16 Ld SOIC	M16.3
HIN202ECBN	0 to 70	16 Ld SOIC (N)	M16.15
HIN202ECBN-T	0 to 70	Tape and Reel	
HIN202ECP	0 to 70	16 Ld PDIP	E16.3
HIN202EIB	-40 to 85	16 Ld SOIC	M16.3
HIN202EIB-T	-40 to 85	Tape and Reel	
HIN202EIBN	-40 to 85	16 Ld SOIC (N)	M16.15
HIN202EIBN-T	-40 to 85	Tape and Reel	
HIN206ECA	0 to 70	24 Ld SSOP	M24.209
HIN206ECB	0 to 70	24 Ld SOIC (W)	M24.3
HIN206ECB-T	0 to 70	Tape and Reel	
HIN206ECP	0 to 70	24 Ld PDIP	E24.3
HIN206EIA	-40 to 85	24 Ld SSOP	M24.209
HIN206EIB	-40 to 85	24 Ld SOIC (W)	M24.3
HIN206EIP	-40 to 85	24 Ld PDIP	E24.3
HIN207ECA	0 to 70	24 Ld SSOP	M24.209
HIN207ECA-T	0 to 70	Tape and Reel	
HIN207ECB	0 to 70	24 Ld SOIC	M24.3
HIN207ECB-T	0 to 70	Tape and Reel	
HIN207ECP	0 to 70	24 Ld PDIP	E24.3
HIN207EIA	-40 to 85	24 Ld SSOP	M24.209
HIN207EIB	-40 to 85	24 Ld SOIC (W)	M24.3
HIN207EIB-T	-40 to 85	Tape and Reel	
HIN207EIP	-40 to 85	24 Ld PDIP	E24.3
HIN208ECA	0 to 70	24 Ld SSOP	M24.209
HIN208ECA-T	0 to 70	Tape and Reel	
HIN208ECB	0 to 70	24 Ld SOIC	M24.3
HIN208ECB-T	0 to 70	Tape and Reel	
HIN208ECP	0 to 70	24 Ld PDIP	E24.3
HIN208EIA	-40 to 85	24 Ld SSOP	M24.209
HIN208EIB	-40 to 85	24 Ld SOIC	M24.3

**Ordering Information (Continued)**

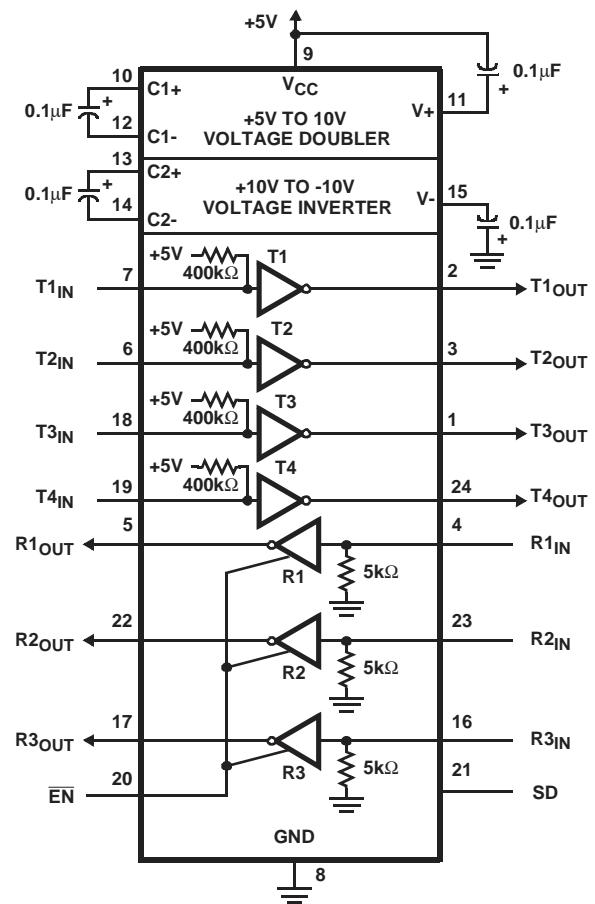
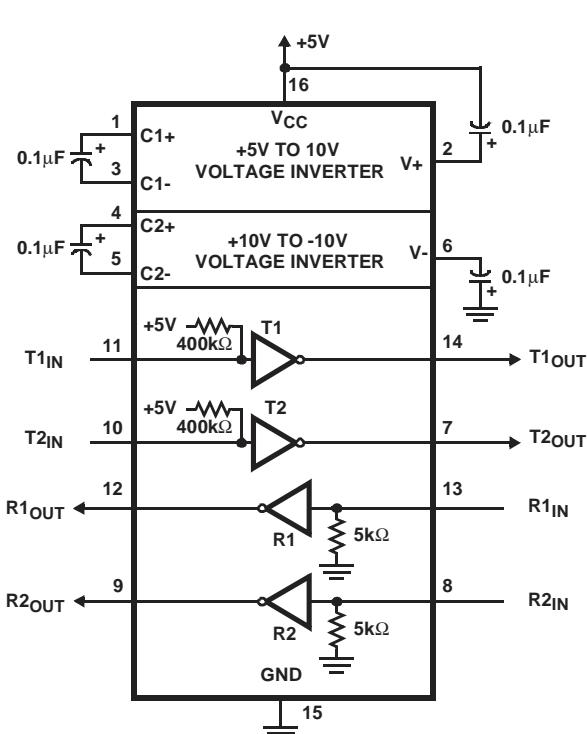
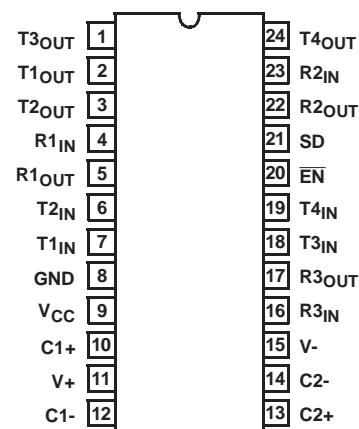
PART NO.	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
HIN208EIP	-40 to 85	24 Ld PDIP	E24.3
HIN211ECA	0 to 70	28 Ld SSOP	M28.209
HIN211ECA-T	0 to 70	Tape and Reel	
HIN211ECB	0 to 70	28 Ld SOIC	M28.3
HIN211EIA	-40 to 85	28 Ld SSOP	M28.209
HIN211EIB	-40 to 85	28 Ld SOIC	M28.3
HIN213ECA	0 to 70	28 Ld SSOP	M28.209
HIN213ECA-T	0 to 70	Tape and Reel	
HIN213ECB	0 to 70	28 Ld SOIC	M28.3
HIN213EIA	-40 to 85	28 Ld SSOP	M28.209
HIN213EIB	-40 to 85	28 Ld SOIC	M28.3
HIN232ECA	0 to 70	16 Ld SSOP	M16.209
HIN232ECB	0 to 70	16 Ld SOIC	M16.3
HIN232ECBN	0 to 70	16 Ld SOIC (N)	M16.15
HIN232ECP	0 to 70	16 Ld PDIP	E16.3
HIN236ECA	0 to 70	24 Ld SSOP	M24.209
HIN236ECB	0 to 70	24 Ld SOIC (W)	M24.3
HIN236ECP	0 to 70	24 Ld PDIP	E24.3
HIN237ECA	0 to 70	24 Ld SSOP	M24.209
HIN237ECB	0 to 70	24 Ld SOIC	M24.3
HIN237ECP	0 to 70	24 Ld PDIP	E24.3
HIN238ECA	0 to 70	24 Ld SSOP	M24.209
HIN238ECB	0 to 70	24 Ld SOIC	M24.3
HIN238ECP	0 to 70	24 Ld PDIP	E24.3
HIN241ECA	0 to 70	28 Ld SSOP	M28.209
HIN241ECB	0 to 70	28 Ld SOIC	M28.3

## Pinouts

HIN202E (PDIP, SOIC)  
TOP VIEW

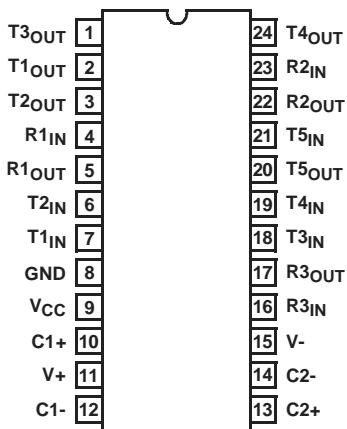


HIN206E (PDIP, SOIC, SSOP)  
TOP VIEW

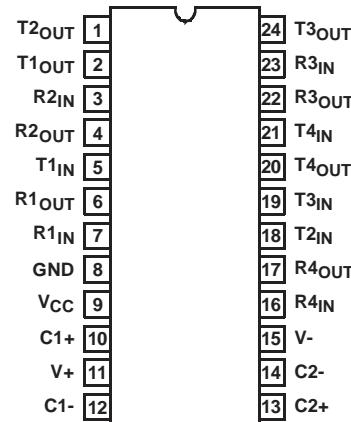


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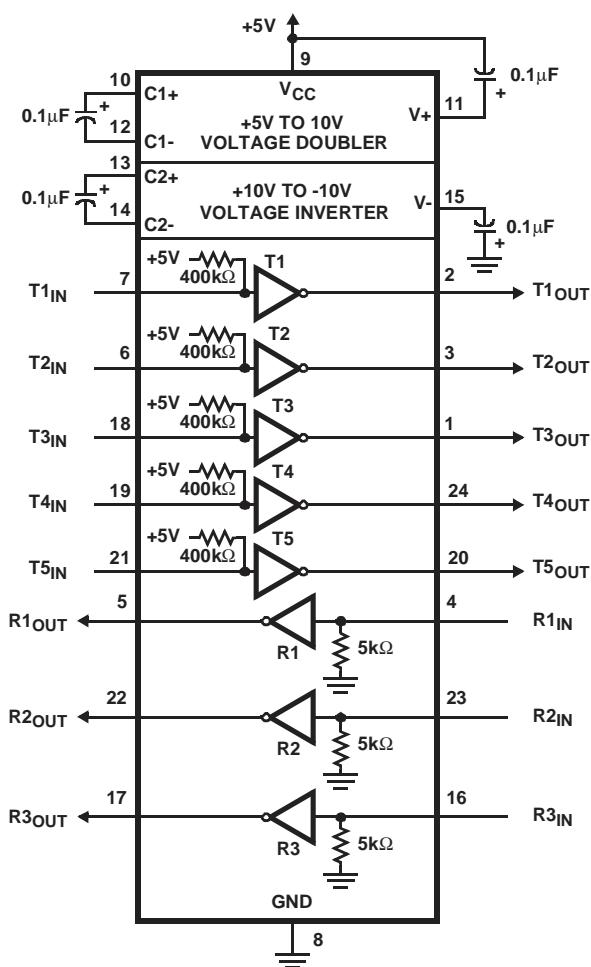
**HIN207E (PDIP, SOIC, SSOP)**  
TOP VIEW



**HIN208E (PDIP, SOIC, SSOP)**  
TOP VIEW



## TOP VIEW



**LM3901 Circuit Diagram**

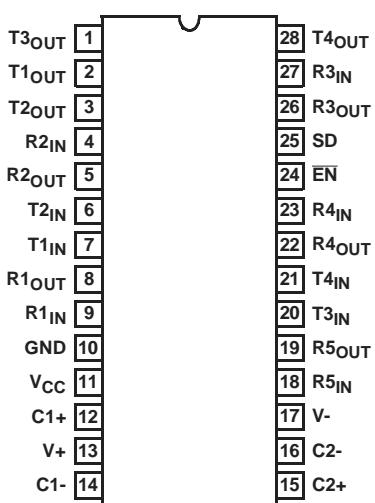
The LM3901 is a monolithic integrated circuit containing a voltage doubler, four operational amplifiers, and four resistive feedback networks.

- Voltage Doubler:** The circuit uses two stages of voltage doubling. Stage 1 (C1+) takes +5V and produces +10V. Stage 2 (C1-) takes +10V and produces -10V. These voltages are supplied to the operational amplifiers.
- Operational Amplifiers:** Four operational amplifiers (T1, T2, T3, T4) are configured as non-inverting amplifiers. Each has a gain of 1 +  $\frac{R_f}{400\text{k}\Omega}$ , where  $R_f$  is the feedback resistor (R1, R2, R3, or R4).
- Feedback Networks:** Each operational amplifier has a feedback network consisting of a resistor ( $R_1, R_2, R_3, R_4$ ) and a 5kΩ pull-down resistor connected to ground.
- Outputs:** The outputs of the operational amplifiers are labeled T1 OUT, T2 OUT, T3 OUT, and T4 OUT.
- Inputs:** The inputs to the operational amplifiers are labeled T1 IN, T2 IN, T3 IN, and T4 IN.
- Power Supply:** The circuit is powered by +5V and +10V to -10V supplies. The ground reference is GND.

**Pinouts (Continued)**

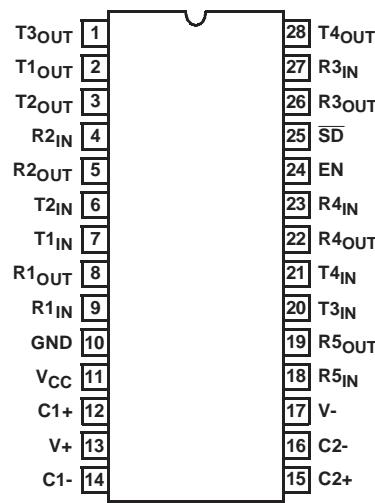
**HIN211E (SOIC, SSOP)**

TOP VIEW

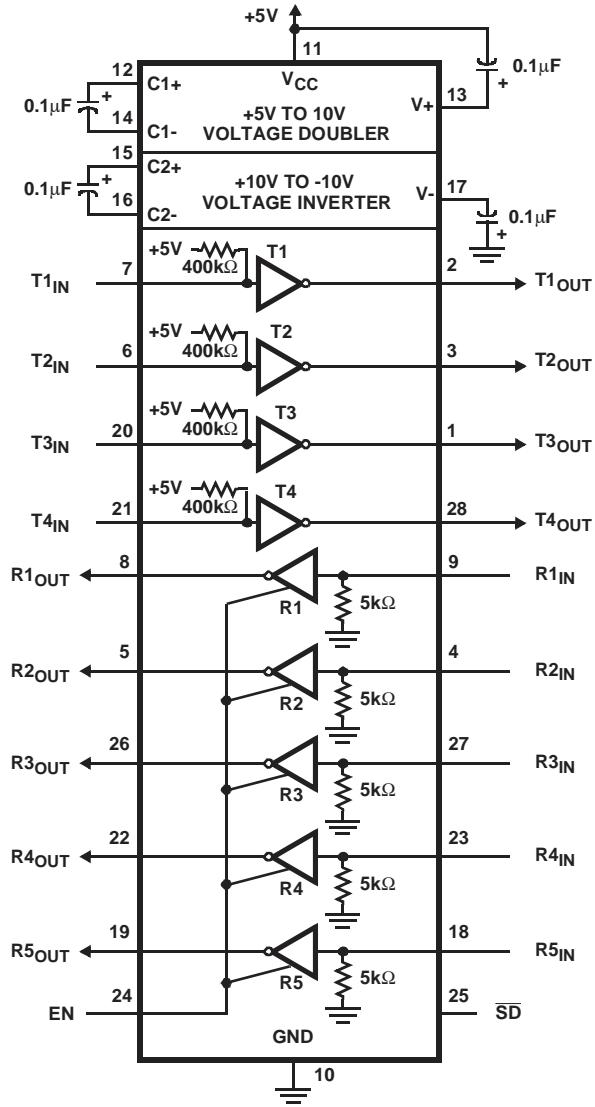
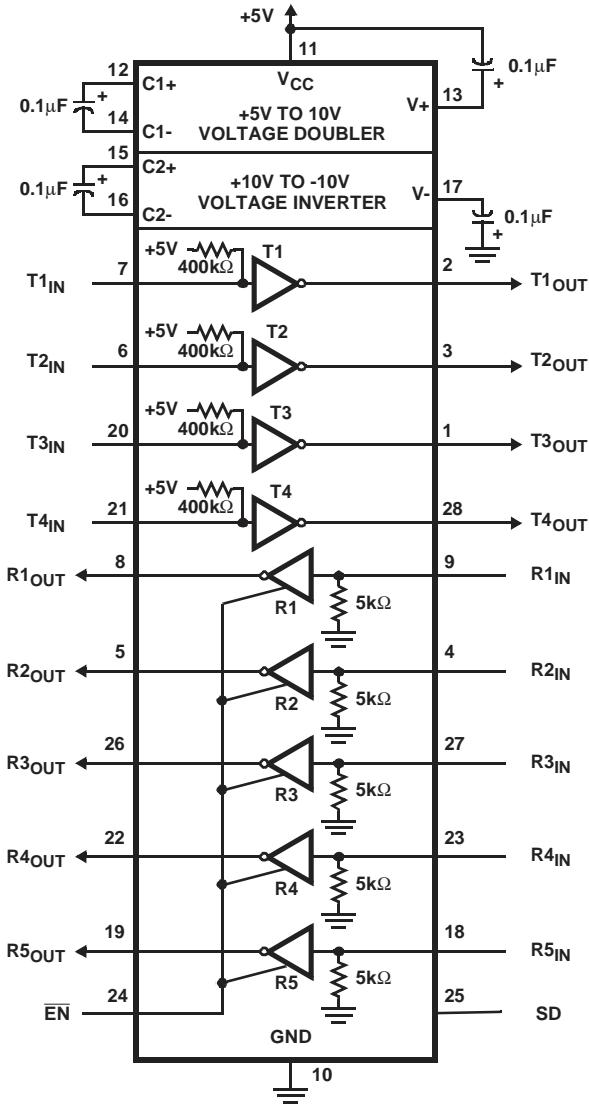


**HIN213E (SOIC, SSOP)**

TOP VIEW

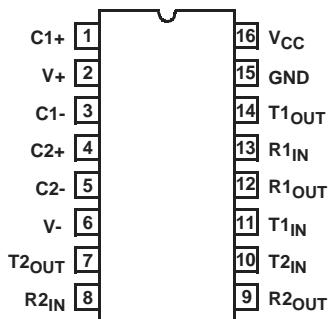


NOTE: R4 and R5 active in shutdown.

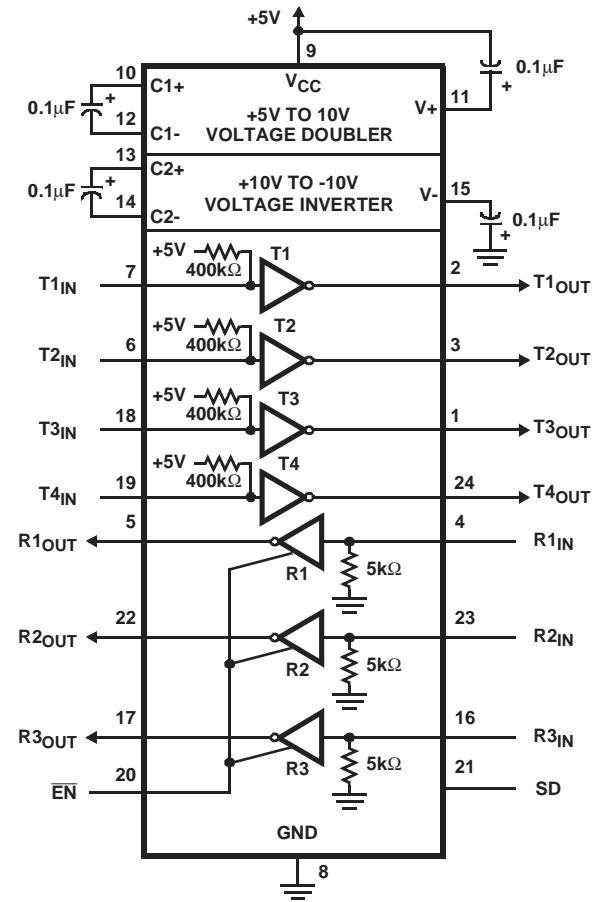
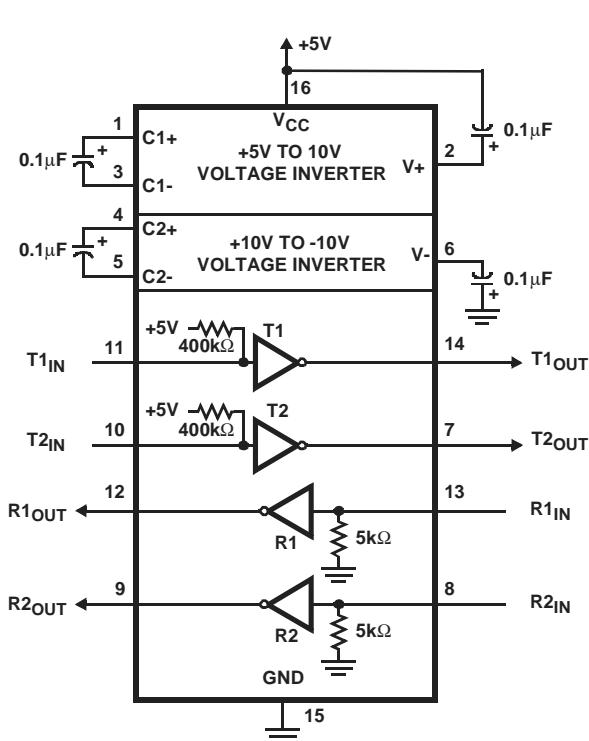
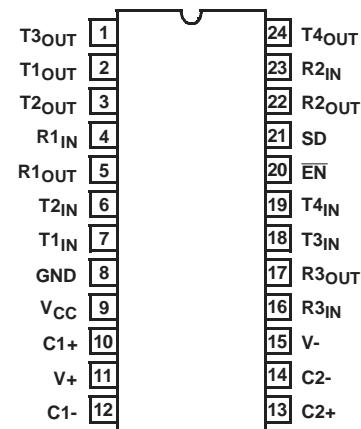


**Pinouts (Continued)**

**HIN232E (PDIP, SOIC)  
TOP VIEW**

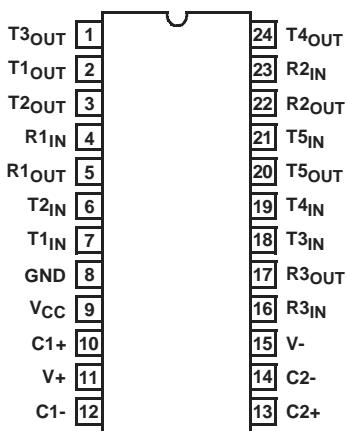


**HIN236E (PDIP, SOIC, SSOP)  
TOP VIEW**

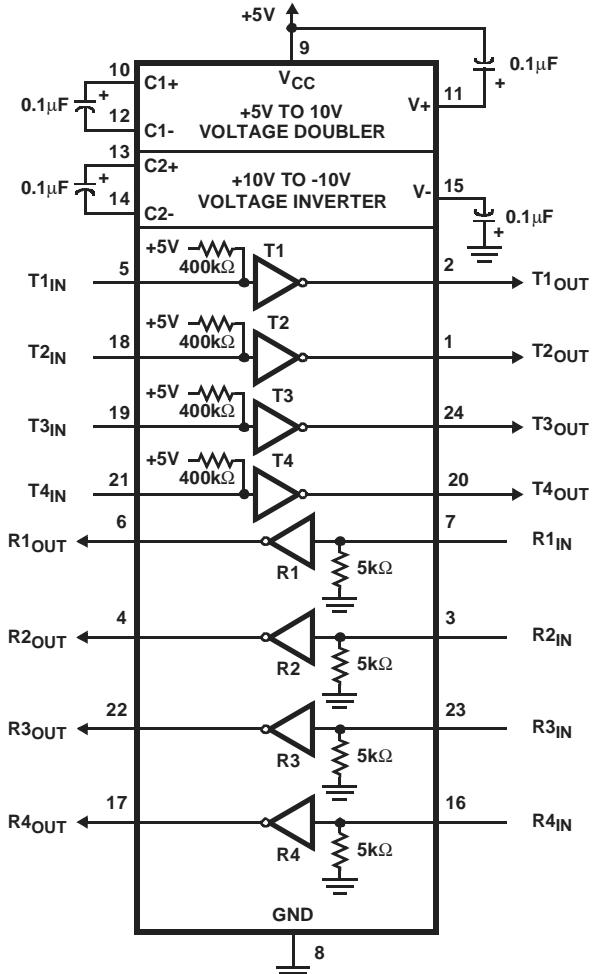
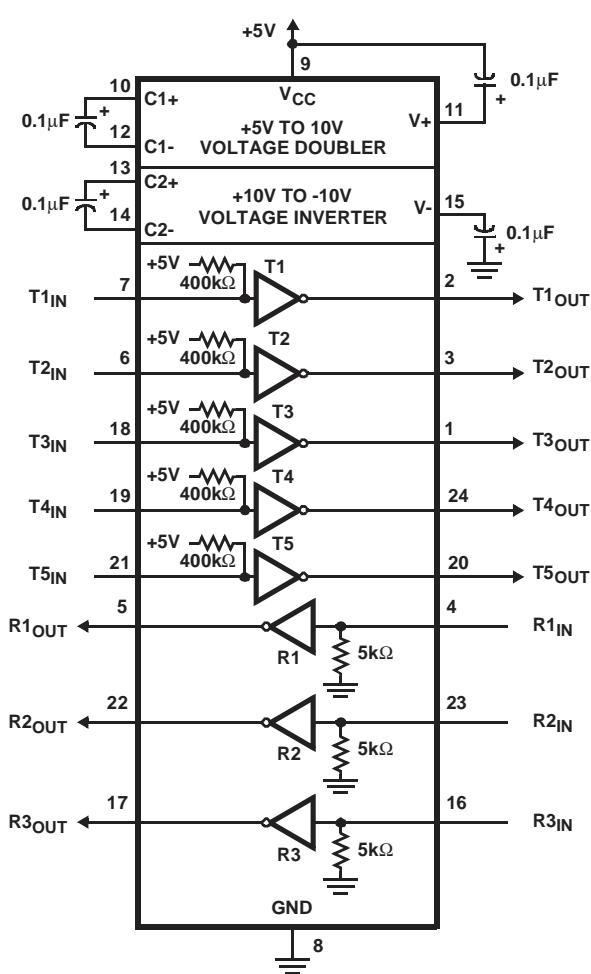
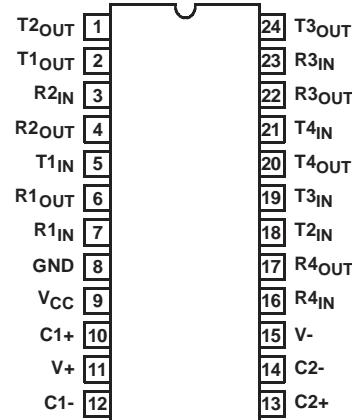


**Pinouts** (Continued)

**HIN237E (PDIP, SOIC, SSOP)**  
TOP VIEW



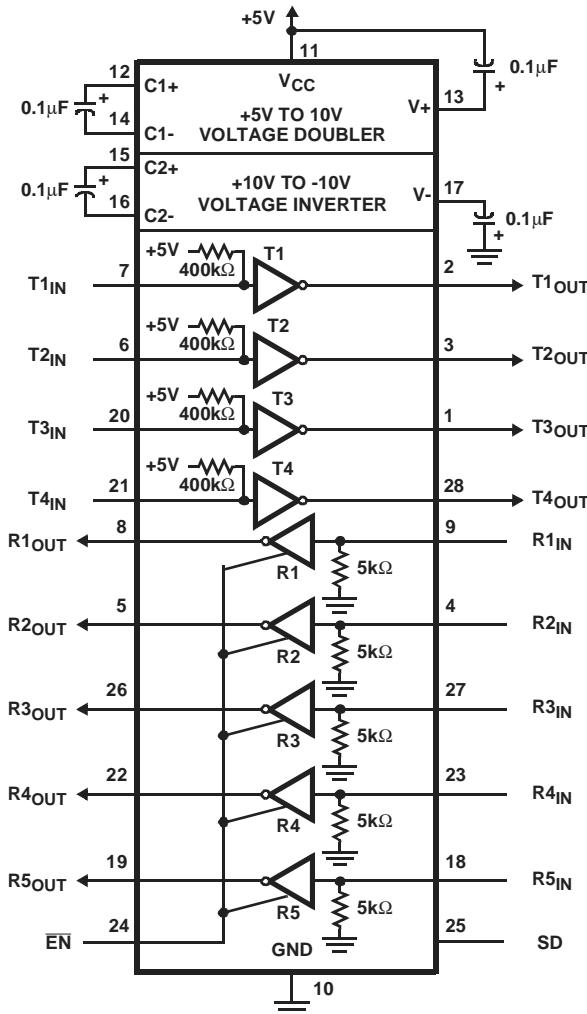
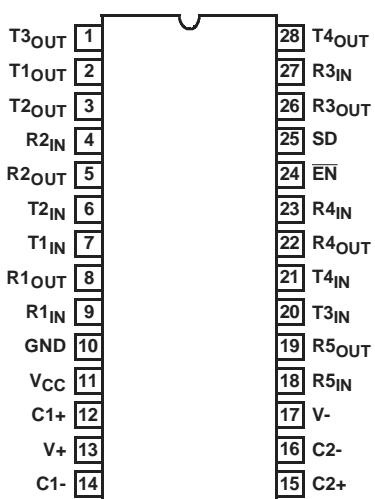
**HIN238E (PDIP, SOIC, SSOP)**  
TOP VIEW



**Pinouts** (Continued)

**HIN241E (SOIC, SSOP)**

TOP VIEW



**Pin Descriptions**

PIN	FUNCTION
V <sub>CC</sub>	Power Supply Input 5V ±10%, (5V ±5% HIN207E).
V+	Internally generated positive supply (+10V nominal).
V-	Internally generated negative supply (-10V nominal).
GND	Ground Lead. Connect to 0V.
C1+	External capacitor (+ terminal) is connected to this lead.
C1-	External capacitor (- terminal) is connected to this lead.
C2+	External capacitor (+ terminal) is connected to this lead.
C2-	External capacitor (- terminal) is connected to this lead.
T <sub>IN</sub>	Transmitter Inputs. These leads accept TTL/CMOS levels. An internal 400kΩ pull-up resistor to V <sub>CC</sub> is connected to each lead.
T <sub>OUT</sub>	Transmitter Outputs. These are RS-232 levels (nominally ±10V).
R <sub>IN</sub>	Receiver Inputs. These inputs accept RS-232 input levels. An internal 5kΩ pull-down resistor to GND is connected to each input.
R <sub>OUT</sub>	Receiver Outputs. These are TTL/CMOS levels.
EN	Enable Input. This is an active low input which enables the receiver outputs. With EN = 5V, the outputs are placed in a high impedance state.
SD, <u>SD</u>	Shutdown Input. With SD = 5V (HIN213E <u>SD</u> = 0V), the charge pump is disabled, the receiver outputs are in a high impedance state (except R4 and R5 of HIN241E) and the transmitters are shut off.
NC	No Connect. No connections are made to these leads.

## Absolute Maximum Ratings

V <sub>CC</sub> to Ground .....	(GND -0.3V) < V <sub>CC</sub> < 6V
V <sub>+</sub> to Ground .....	(V <sub>CC</sub> -0.3V) < V <sub>+</sub> < 12V
V <sub>-</sub> to Ground .....	-12V < V <sub>-</sub> < (GND +0.3V)
Input Voltages	
T <sub>IN</sub> .....	-0.3V < V <sub>IN</sub> < (V <sub>+</sub> +0.3V)
R <sub>IN</sub> .....	±30V
Output Voltages	
T <sub>OUT</sub> .....	(V <sub>-</sub> -0.3V) < V <sub>TXOUT</sub> < (V <sub>+</sub> +0.3V)
R <sub>OUT</sub> .....	(GND -0.3V) < V <sub>RXOUT</sub> < (V <sub>+</sub> +0.3V)
Short Circuit Duration	
T <sub>OUT</sub> .....	Continuous
R <sub>OUT</sub> .....	Continuous
ESD Classification .....	See Specification Table

## Operating Conditions

Temperature Range	
HIN2XXCX .....	0°C to 70°C
HIN2XXIX .....	-40°C to 85°C

**CAUTION:** Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

## NOTE:

1. θ<sub>JA</sub> is measured with the component mounted on an evaluation PC board in free air.

## Electrical Specifications

Test Conditions: V<sub>CC</sub> = +5V ±10%, (V<sub>CC</sub> = +5V ±5% HIN207E); C1-C4 = 0.1μF; T<sub>A</sub> = Operating Temperature Range

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNITS
<b>SUPPLY CURRENTS</b>						
Power Supply Current, I <sub>CC</sub>	No Load, T <sub>A</sub> = 25°C	HIN202E	-	8	15	mA
		HIN206E - HIN208E, HIN211E, HIN213E, HIN236E - HIN241E	-	11	20	mA
		HIN232E	-	5	10	mA
Shutdown Supply Current, I <sub>CC(SD)</sub>	T <sub>A</sub> = 25°C	HIN206E, HIN211E, HIN236E, HIN241E	-	1	10	μA
		HIN213E	-	15	50	μA
<b>LOGIC AND TRANSMITTER INPUTS, RECEIVER OUTPUTS</b>						
Input Logic Low, V <sub>IL</sub>	T <sub>IN</sub> , $\overline{EN}$ , SD, EN, $\overline{SD}$		-	-	0.8	V
Input Logic High, V <sub>IH</sub>	T <sub>IN</sub>		2.0	-	-	V
	$\overline{EN}$ , SD, EN, $\overline{SD}$		2.4	-	-	V
Transmitter Input Pullup Current, I <sub>P</sub>	T <sub>IN</sub> = 0V		-	15	200	μA
TTL/CMOS Receiver Output Voltage Low, V <sub>OL</sub>	I <sub>OUT</sub> = 1.6mA (HIN202E, HIN232E, I <sub>OUT</sub> = 3.2mA)		-	0.1	0.4	V
TTL/CMOS Receiver Output Voltage High, V <sub>OH</sub>	I <sub>OUT</sub> = -1mA		3.5	4.6	-	V
TTL/CMOS Receiver Output Leakage	$\overline{EN}$ = V <sub>CC</sub> , EN = 0, 0V < R <sub>OUT</sub> < V <sub>CC</sub>		-	0.5	±10	μA
<b>RECEIVER INPUTS</b>						
RS-232 Input Voltage Range, V <sub>IN</sub>			-30	-	+30	V
Receiver Input Impedance, R <sub>IN</sub>	T <sub>A</sub> = 25°C, V <sub>IN</sub> = ±3V		3.0	5.0	7.0	kΩ
Receiver Input Low Threshold, V <sub>IN</sub> (H-L)	V <sub>CC</sub> = 5V, T <sub>A</sub> = 25°C	Active Mode	-	1.2	-	V
		Shutdown Mode HIN213E R4 and R5	-	1.5	-	V
Receiver Input High Threshold, V <sub>IN</sub> (L-H)	V <sub>CC</sub> = 5V, T <sub>A</sub> = 25°C	Active Mode	-	1.7	2.4	V
		Shutdown Mode HIN213E R4 and R5	-	1.5	2.4	V
Receiver Input Hysteresis, V <sub>HYST</sub>	V <sub>CC</sub> = 5V, No Hysteresis in Shutdown Mode		0.2	0.5	1.0	V

## Thermal Information

Thermal Resistance (Typical, Note 1)	θ <sub>JA</sub> (°C/W)
16 Ld SOIC (N) Package .....	110
16 Ld SOIC (W) Package .....	100
16 Ld SSOP Package .....	155
16 Ld PDIP Package .....	90
24 Ld SOIC Package .....	75
24 Ld SSOP Package .....	135
24 Ld PDIP (N) Package .....	75
24 Ld PDIP (W) Package .....	55
28 Ld SOIC Package .....	70
28 Ld SSOP Package .....	100
Maximum Junction Temperature (Plastic Package) .....	150°C
Maximum Storage Temperature Range .....	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s) .....	300°C (SOIC and SSOP - Lead Tips Only)

## HIN202E thru HIN241E

**Electrical Specifications** Test Conditions:  $V_{CC} = +5V \pm 10\%$ , ( $V_{CC} = +5V \pm 5\%$  HIN207E); C1-C4 =  $0.1\mu F$ ;  $T_A$  = Operating Temperature Range **(Continued)**

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>TIMING CHARACTERISTICS</b>					
Output Enable Time, $t_{EN}$	HIN206E, HIN211E, HIN213E, HIN236E, HIN241E	-	600	-	ns
Output Disable Time, $t_{DIS}$	HIN206E, HIN211E, HIN213E, HIN236E, HIN241E	-	200	-	ns
Transmitter, Receiver Propagation Delay, $t_{PD}$	HIN213E $\overline{SD} = 0V$ , R4, R5	-	4.0	40	$\mu s$
	HIN213E $\overline{SD} = V_{CC}$ , R1 - R5	-	0.5	10	$\mu s$
	All except HIN213E	-	0.5	10	$\mu s$
Transition Region Slew Rate, $SR_T$	$R_L = 3k\Omega$ , $C_L = 1000pF$ Measured from +3V to -3V or -3V to +3V, 1 Transmitter Switching (Note 2)	3	20	45	V/ $\mu s$
<b>TRANSMITTER OUTPUTS</b>					
Output Voltage Swing, $T_{OUT}$	Transmitter Outputs, $3k\Omega$ to Ground	$\pm 5$	$\pm 9$	$\pm 10$	V
Output Resistance, $R_{OUT}$	$V_{CC} = V+ = V- = 0V$ , $V_{OUT} = \pm 2V$	300	-	-	$\Omega$
RS-232 Output Short Circuit Current, $I_{SC}$	$T_{OUT}$ Shorted to GND	-	$\pm 10$	-	mA
<b>ESD PERFORMANCE</b>					
RS-232 Pins ( $T_{OUT}$ , $R_{IN}$ )	Human Body Model	-	$\pm 15$	-	kV
	IEC1000-4-2 Contact Discharge	-	$\pm 8$	-	kV
	IEC1000-4-2 Air Gap (Note 3)	-	$\pm 15$	-	kV
All Other Pins	Human Body Model	-	$\pm 2$	-	kV

NOTES:

2. Guaranteed by design.
3. Meets Level 4.

## Test Circuits (HIN232E)

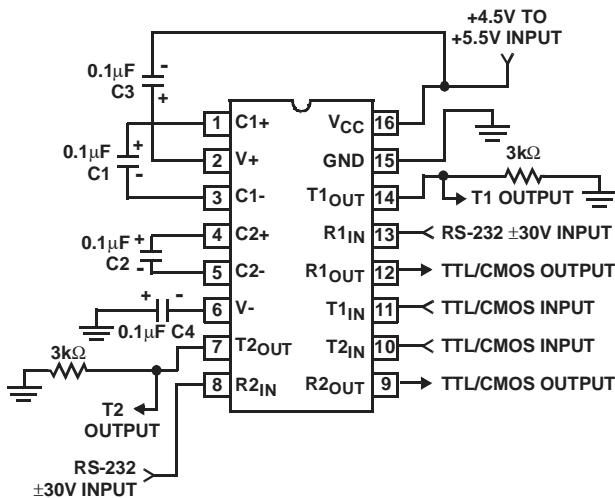


FIGURE 1. GENERAL TEST CIRCUIT

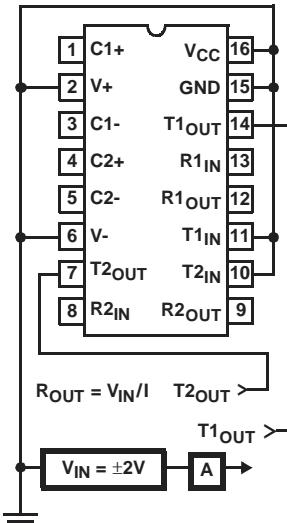


FIGURE 2. POWER-OFF SOURCE RESISTANCE CONFIGURATION

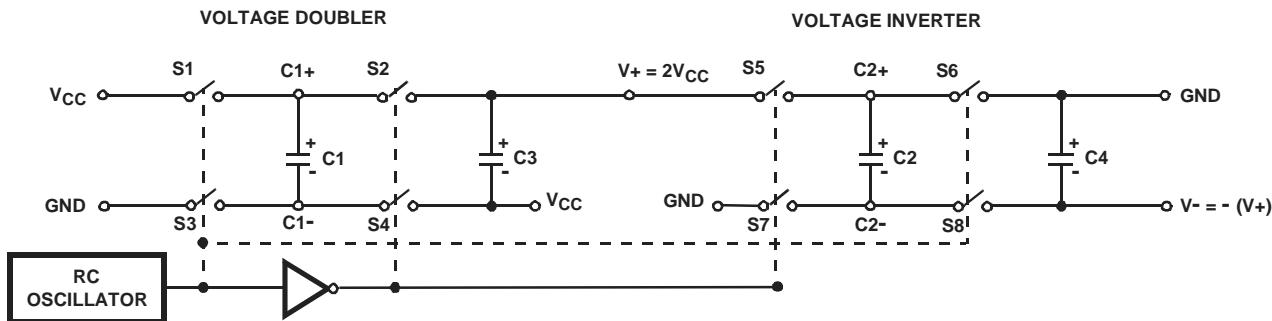


FIGURE 3. CHARGE PUMP

## Detailed Description

The HIN2XXE family of high-speed RS-232 transmitters/receivers are powered by a single +5V power supply, feature low power consumption, and meet all EIA RS232C and V.28 specifications. The circuit is divided into three sections: the charge pump, transmitter, and receiver.

### Charge Pump

An equivalent circuit of the charge pump is illustrated in Figure 3. The charge pump contains two sections: the voltage doubler and the voltage inverter. Each section is driven by a two phase, internally generated clock to generate +10V and -10V. The nominal clock frequency is 125kHz. During phase one of the clock, capacitor C1 is charged to  $V_{CC}$ . During phase two, the voltage on C1 is added to  $V_{CC}$ , producing a signal across C3 equal to twice  $V_{CC}$ . During phase two, C2 is also charged to  $2V_{CC}$ , and then during phase one, it is inverted with respect to ground to produce a signal across C4 equal to  $-2V_{CC}$ . The charge pump accepts input voltages up to 5.5V. The output

impedance of the voltage doubler section ( $V+$ ) is approximately  $200\Omega$ , and the output impedance of the voltage inverter section ( $V-$ ) is approximately  $450\Omega$ . A typical application uses  $0.1\mu F$  capacitors for C1-C4, however, the value is not critical. Increasing the values of C1 and C2 will lower the output impedance of the voltage doubler and inverter, increasing the values of the reservoir capacitors, C3 and C4, lowers the ripple on the  $V+$  and  $V-$  supplies.

During shutdown mode (HIN206E, HIN211E, HIN213E, HIN236E and HIN241E) the charge pump is turned off,  $V+$  is pulled down to  $V_{CC}$ ,  $V-$  is pulled up to GND, and the supply current is reduced to less than  $10\mu A$ . The transmitter outputs are disabled and the receiver outputs (except for HIN213E, R4 and R5) are placed in the high impedance state.

### Transmitters

The transmitters are TTL/CMOS compatible inverters which translate the inputs to RS-232 outputs. The input logic threshold is about 26% of  $V_{CC}$ , or 1.3V for  $V_{CC} = 5V$ . A logic 1 at the input results in a voltage of between -5V and  $V-$  at

the output, and a logic 0 results in a voltage between +5V and (V+ - 0.6V). Each transmitter input has an internal 400k $\Omega$  pullup resistor so any unused input can be left unconnected and its output remains in its low state. The output voltage swing meets the RS-232C specifications of  $\pm 5V$  minimum with the worst case conditions of: all transmitters driving 3k $\Omega$  minimum load impedance,  $V_{CC} = 4.5V$ , and maximum allowable operating temperature. The transmitters have an internally limited output slew rate which is less than 30V/ $\mu s$ . The outputs are short circuit protected and can be shorted to ground indefinitely. The powered down output impedance is a minimum of 300 $\Omega$  with  $\pm 2V$  applied to the outputs and  $V_{CC} = 0V$ .

### Receivers

The receiver inputs accept up to  $\pm 30V$  while presenting the required 3k $\Omega$  to 7k $\Omega$  input impedance even if the power is off ( $V_{CC} = 0V$ ). The receivers have a typical input threshold of 1.3V which is within the  $\pm 3V$  limits, known as the transition region, of the RS-232 specifications. The receiver output is 0V to  $V_{CC}$ . The output will be low whenever the input is greater than 2.4V and high whenever the input is floating or driven between +0.8V and -30V. The receivers feature 0.5V hysteresis (except during shutdown) to improve noise rejection. The receiver Enable line  $\overline{EN}$ , (EN on HIN213E) when unasserted, disables the receiver outputs, placing them in the high impedance mode. The receiver outputs are also placed in the high impedance state when in shutdown mode (except HIN213E R4 and R5).

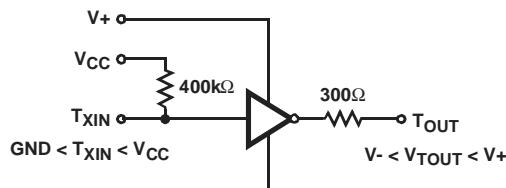


FIGURE 4. TRANSMITTER

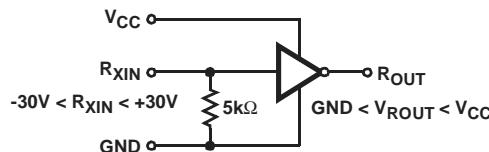


FIGURE 5. RECEIVER

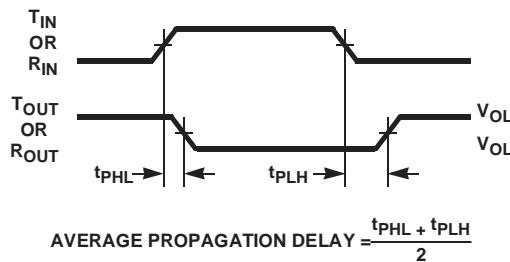


FIGURE 6. PROPAGATION DELAY DEFINITION

### HIN213E Operation in Shutdown

The HIN213E features two receivers, R4 and R5, which remain active in shutdown mode. During normal operation the receivers propagation delay is typically 0.5 $\mu s$ . This propagation delay may increase slightly during shutdown. When entering shut down mode, receivers R4 and R5 are not valid for 80 $\mu s$  after  $\overline{SD} = V_{IL}$ . When exiting shutdown mode, all receiver outputs will be invalid until the charge pump circuitry reaches normal operating voltage. This is typically less than 2ms when using 0.1 $\mu F$  capacitors.

### Application Information

The HIN2XXE may be used for all RS-232 data terminal and communication links. It is particularly useful in applications where  $\pm 12V$  power supplies are not available for conventional RS-232 interface circuits. The applications presented represent typical interface configurations.

A simple duplex RS-232 port with CTS/RTS handshaking is illustrated in Figure 7. Fixed output signals such as DTR (data terminal ready) and DSRS (data signaling rate select) is generated by driving them through a 5k $\Omega$  resistor connected to V+.

In applications requiring four RS-232 inputs and outputs (Figure 8), note that each circuit requires two charge pump capacitors (C1 and C2) but can share common reservoir capacitors (C3 and C4). The benefit of sharing common reservoir capacitors is the elimination of two capacitors and the reduction of the charge pump source impedance which effectively increases the output swing of the transmitters.

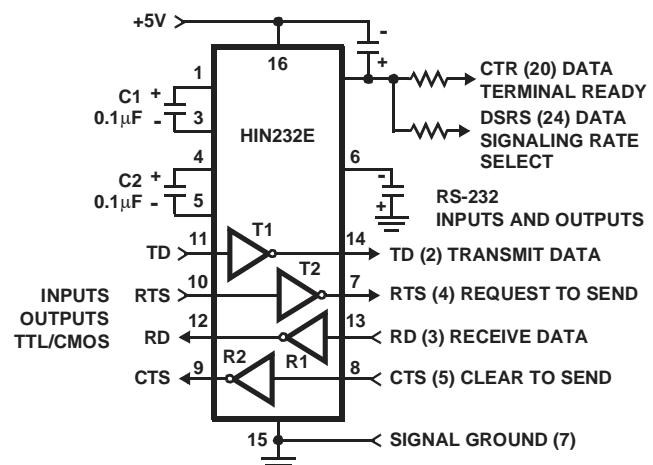


FIGURE 7. SIMPLE DUPLEX RS-232 PORT WITH CTS/RTS HANDSHAKING

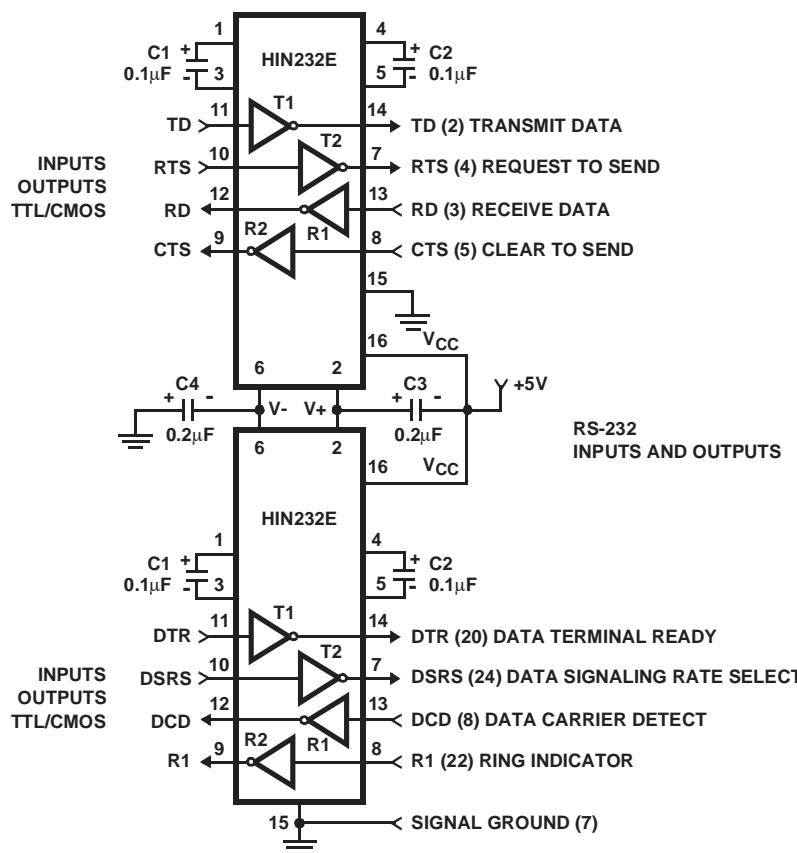


FIGURE 8. COMBINING TWO HIN232Es FOR 4 PAIRS OF RS-232 INPUTS AND OUTPUTS

### Typical Performance Curves

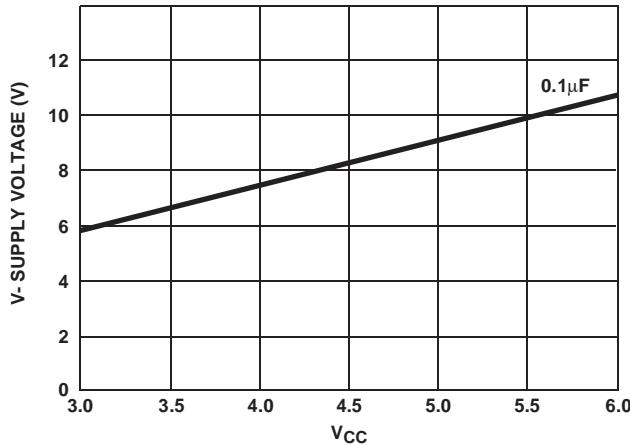


FIGURE 9. V- SUPPLY VOLTAGE vs V<sub>CC</sub>

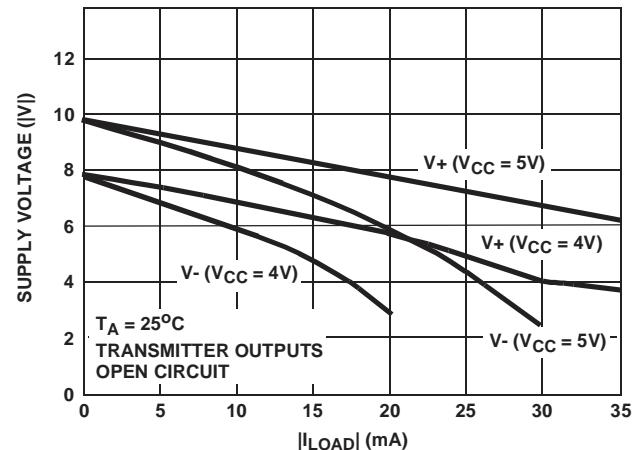


FIGURE 10. V+, V- OUTPUT VOLTAGE vs LOAD

## **Die Characteristics**

### **DIE DIMENSIONS:**

128 mils x 77 mils

### **METALLIZATION:**

Type: Al  
Thickness:  $10\text{k}\text{\AA} \pm 1\text{k}\text{\AA}$

### **SUBSTRATE POTENTIAL**

GND

### **PASSIVATION:**

Type: Nitride over Silox  
Nitride Thickness:  $8\text{k}\text{\AA}$   
Silox Thickness:  $7\text{k}\text{\AA}$

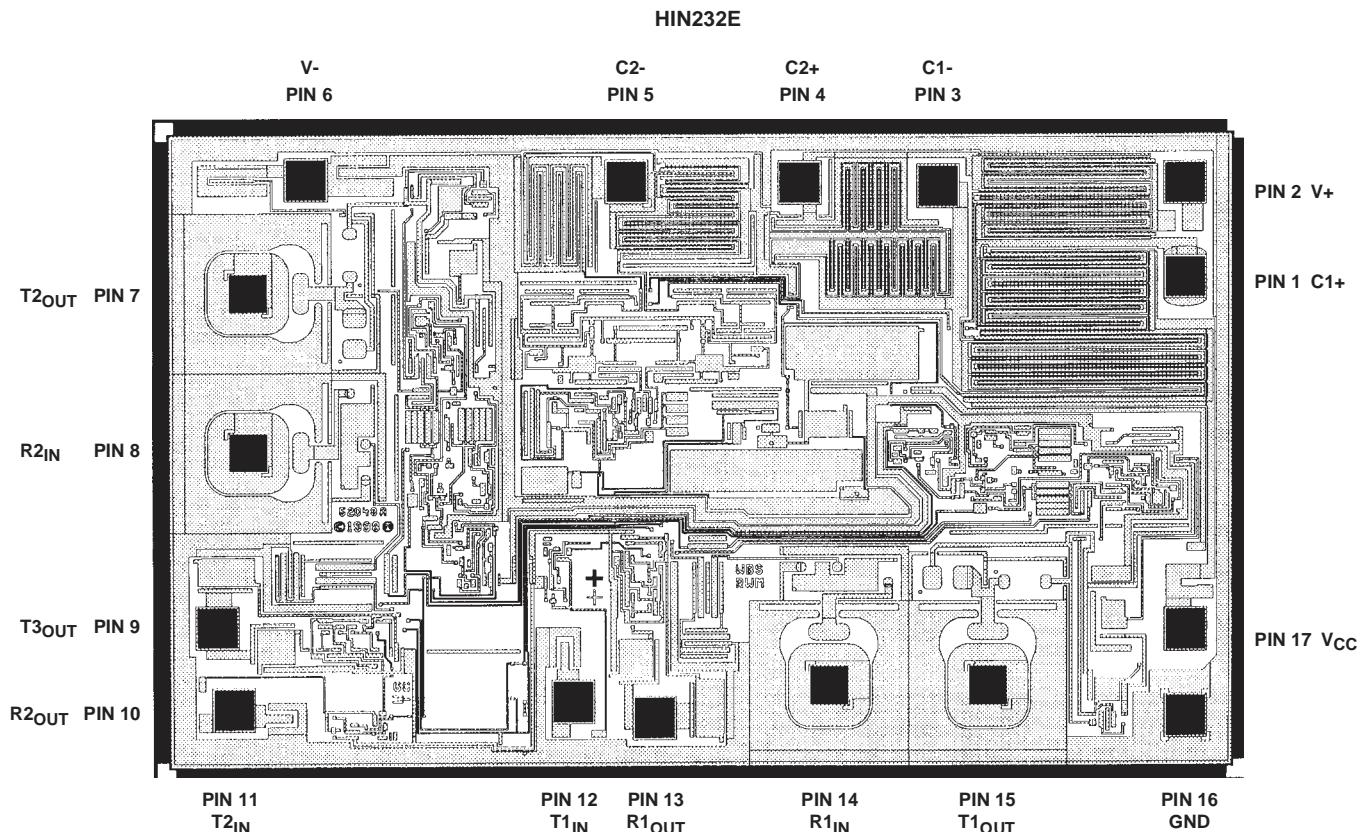
### **TRANSISTOR COUNT:**

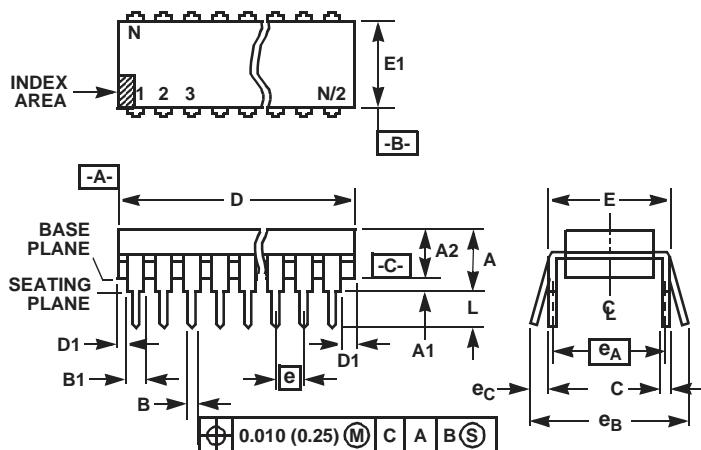
185

### **PROCESS:**

CMOS Metal Gate

## **Metallization Mask Layout**



**Dual-In-Line Plastic Packages (PDIP)**

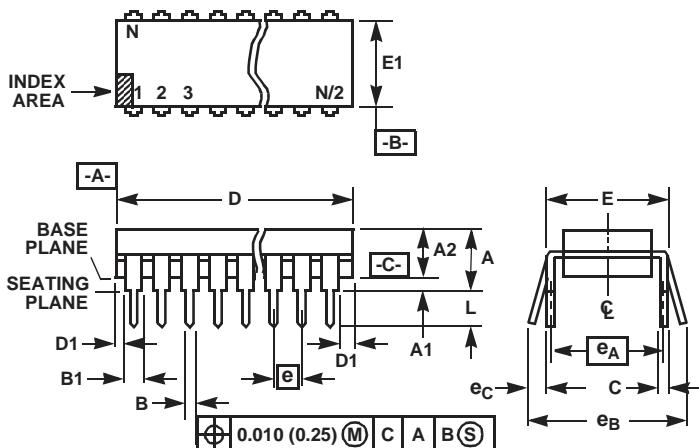
## NOTES:

1. Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
4. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
5. D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
6. E and  $e_A$  are measured with the leads constrained to be perpendicular to datum  $-C-$ .
7.  $e_B$  and  $e_C$  are measured at the lead tips with the leads unconstrained.  $e_C$  must be zero or greater.
8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
9. N is the maximum number of terminal positions.
10. Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

**E16.3 (JEDEC MS-001-BB ISSUE D)  
16 LEAD DUAL-IN-LINE PLASTIC PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
B	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8, 10
C	0.008	0.014	0.204	0.355	-
D	0.735	0.775	18.66	19.68	5
D1	0.005	-	0.13	-	5
E	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
e	0.100 BSC		2.54 BSC		-
$e_A$	0.300 BSC		7.62 BSC		6
$e_B$	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
N	16		16		9

Rev. 0 12/93

**Dual-In-Line Plastic Packages (PDIP)**

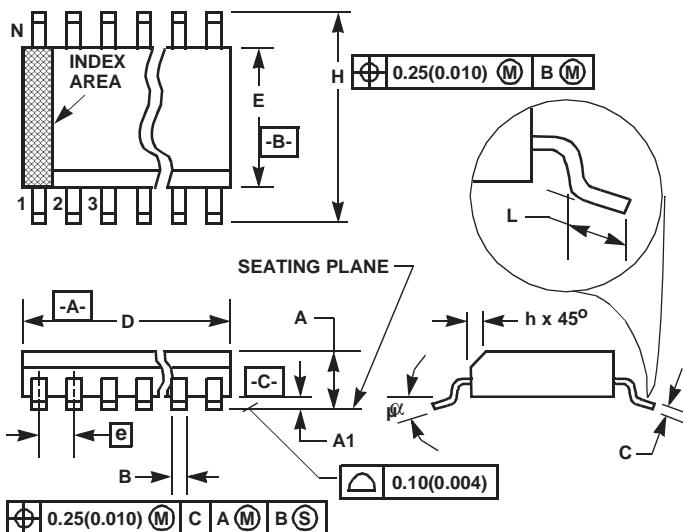
## NOTES:

- Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- E and  $e_A$  are measured with the leads constrained to be perpendicular to datum  $-C-$ .
- $e_B$  and  $e_C$  are measured at the lead tips with the leads unconstrained.  $e_C$  must be zero or greater.
- B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- N is the maximum number of terminal positions.
- Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

**E24.3 (JEDEC MS-001-AF ISSUE D)**  
24 LEAD NARROW BODY DUAL-IN-LINE PLASTIC  
PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
B	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8
C	0.008	0.014	0.204	0.355	-
D	1.230	1.280	31.24	32.51	5
D1	0.005	-	0.13	-	5
E	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
e	0.100 BSC		2.54 BSC		-
$e_A$	0.300 BSC		7.62 BSC		6
$e_B$	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
N	24		24		9

Rev. 0 12/93

**Small Outline Plastic Packages (SOIC)**

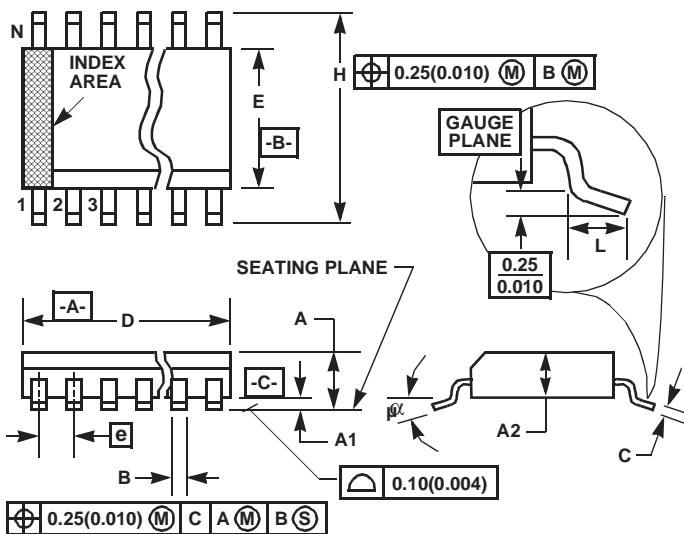
## NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

**M16.15 (JEDEC MS-012-AC ISSUE C)  
16 LEAD NARROW BODY SMALL OUTLINE PLASTIC  
PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.0532	0.0688	1.35	1.75	-
A1	0.0040	0.0098	0.10	0.25	-
B	0.013	0.020	0.33	0.51	9
C	0.0075	0.0098	0.19	0.25	-
D	0.3859	0.3937	9.80	10.00	3
E	0.1497	0.1574	3.80	4.00	4
e	0.050 BSC		1.27 BSC		-
H	0.2284	0.2440	5.80	6.20	-
h	0.0099	0.0196	0.25	0.50	5
L	0.016	0.050	0.40	1.27	6
N	16		16		7
$\alpha$	$0^\circ$	$8^\circ$	$0^\circ$	$8^\circ$	-

Rev. 0 12/93

**Small Outline Plastic Packages (SSOP)**

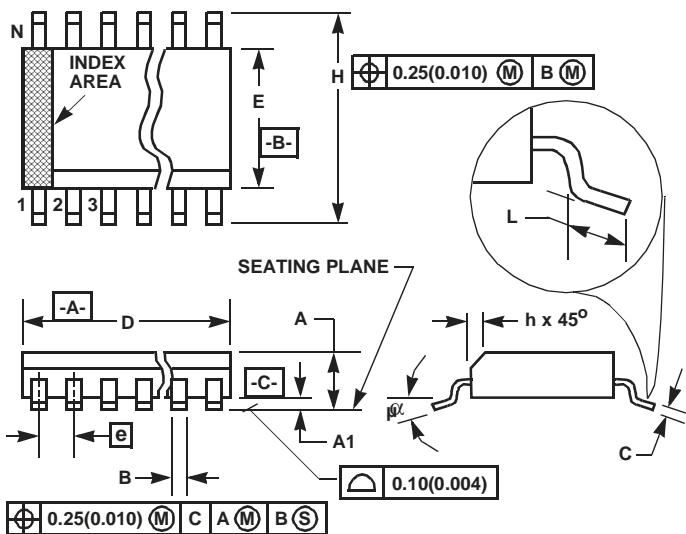
**M16.209 (JEDEC MO-150-AC ISSUE B)  
16 LEAD SHRINK SMALL OUTLINE PLASTIC PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.078	-	2.00	-
A1	0.002	-	0.05	-	-
A2	0.065	0.072	1.65	1.85	-
B	0.009	0.014	0.22	0.38	9
C	0.004	0.009	0.09	0.25	-
D	0.233	0.255	5.90	6.50	3
E	0.197	0.220	5.00	5.60	4
e	0.026 BSC		0.65 BSC		-
H	0.292	0.322	7.40	8.20	-
L	0.022	0.037	0.55	0.95	6
N	16		16		7
$\alpha$	$0^\circ$	$8^\circ$	$0^\circ$	$8^\circ$	-

Rev. 2 3/95

## NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.20mm (0.0078 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.20mm (0.0078 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. Dimension "B" does not include dambar protrusion. Allowable dambar protrusion shall be 0.13mm (0.005 inch) total in excess of "B" dimension at maximum material condition.
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

**Small Outline Plastic Packages (SOIC)**

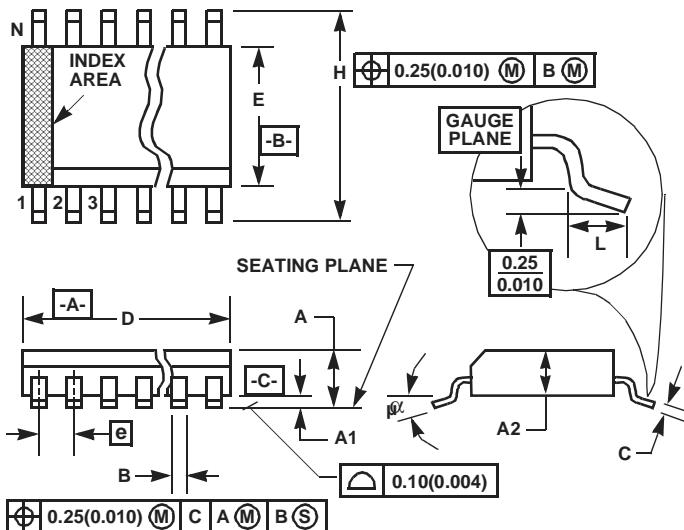
## NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch)
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

**M16.3 (JEDEC MS-013-AA ISSUE C)**  
16 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.0926	0.1043	2.35	2.65	-
A1	0.0040	0.0118	0.10	0.30	-
B	0.013	0.0200	0.33	0.51	9
C	0.0091	0.0125	0.23	0.32	-
D	0.3977	0.4133	10.10	10.50	3
E	0.2914	0.2992	7.40	7.60	4
e	0.050 BSC		1.27 BSC		-
H	0.394	0.419	10.00	10.65	-
h	0.010	0.029	0.25	0.75	5
L	0.016	0.050	0.40	1.27	6
N	16		16		7
$\alpha$	$0^\circ$	$8^\circ$	$0^\circ$	$8^\circ$	-

Rev. 0 12/93

**Shrink Small Outline Plastic Packages (SSOP)**

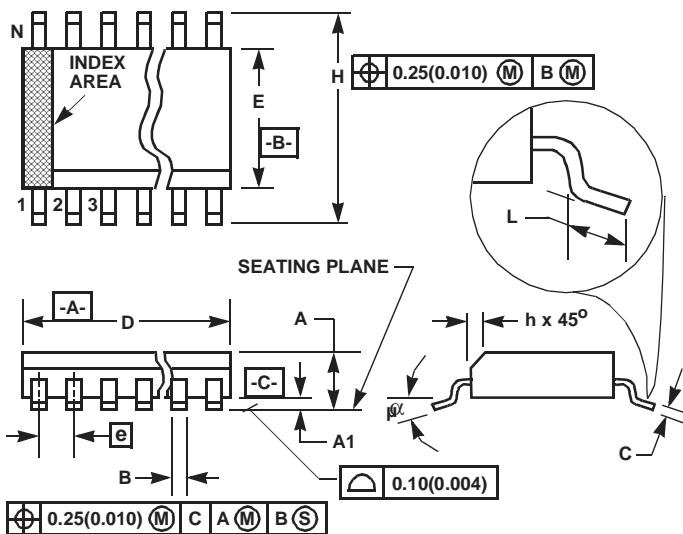
## NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.20mm (0.0078 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.20mm (0.0078 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. Dimension "B" does not include dambar protrusion. Allowable dambar protrusion shall be 0.13mm (0.005 inch) total in excess of "B" dimension at maximum material condition.
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

**M24.209 (JEDEC MO-150-AG ISSUE B)  
24 LEAD SHRINK SMALL OUTLINE PLASTIC PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.078	-	2.00	-
A1	0.002	-	0.05	-	-
A2	0.065	0.072	1.65	1.85	-
B	0.009	0.014	0.22	0.38	9
C	0.004	0.009	0.09	0.25	-
D	0.312	0.334	7.90	8.50	3
E	0.197	0.220	5.00	5.60	4
e	0.026 BSC		0.65 BSC		-
H	0.292	0.322	7.40	8.20	-
L	0.022	0.037	0.55	0.95	6
N	24		24		7
$\alpha$	$0^\circ$	$8^\circ$	$0^\circ$	$8^\circ$	-

Rev. 1 3/95

**Small Outline Plastic Packages (SOIC)**

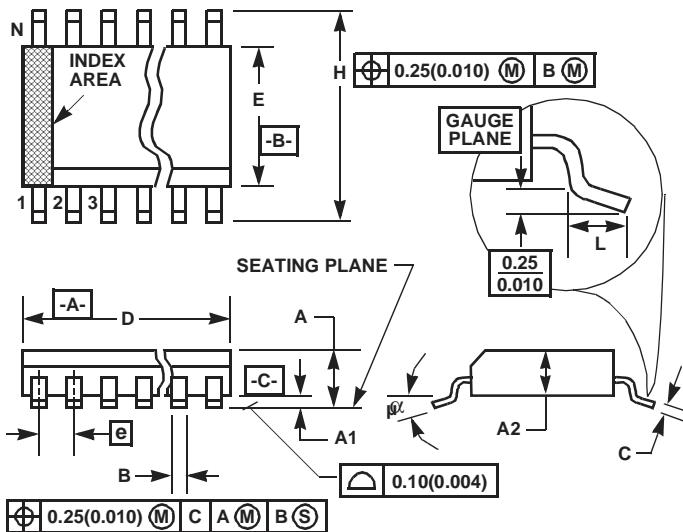
## NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch)
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

**M24.3 (JEDEC MS-013-AD ISSUE C)**  
**24 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.0926	0.1043	2.35	2.65	-
A1	0.0040	0.0118	0.10	0.30	-
B	0.013	0.020	0.33	0.51	9
C	0.0091	0.0125	0.23	0.32	-
D	0.5985	0.6141	15.20	15.60	3
E	0.2914	0.2992	7.40	7.60	4
e	0.05 BSC		1.27 BSC		-
H	0.394	0.419	10.00	10.65	-
h	0.010	0.029	0.25	0.75	5
L	0.016	0.050	0.40	1.27	6
N	24		24		7
$\alpha$	$0^\circ$	$8^\circ$	$0^\circ$	$8^\circ$	-

Rev. 0 12/93

**Shrink Small Outline Plastic Packages (SSOP)**

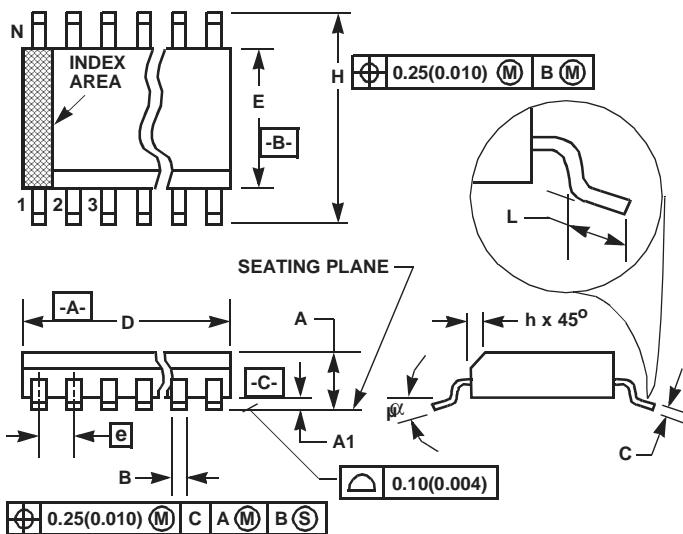
## NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.20mm (0.0078 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.20mm (0.0078 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. Dimension "B" does not include dambar protrusion. Allowable dambar protrusion shall be 0.13mm (0.005 inch) total in excess of "B" dimension at maximum material condition.
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

**M28.209 (JEDEC MO-150-AH ISSUE B)  
28 LEAD SHRINK SMALL OUTLINE PLASTIC PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.078	-	2.00	-
A1	0.002	-	0.05	-	-
A2	0.065	0.072	1.65	1.85	-
B	0.009	0.014	0.22	0.38	9
C	0.004	0.009	0.09	0.25	-
D	0.390	0.413	9.90	10.50	3
E	0.197	0.220	5.00	5.60	4
e	0.026 BSC		0.65 BSC		-
H	0.292	0.322	7.40	8.20	-
L	0.022	0.037	0.55	0.95	6
N	28		28		7
$\alpha$	$0^\circ$	$8^\circ$	$0^\circ$	$8^\circ$	-

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**Small Outline Plastic Packages (SOIC)**

## NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

**M28.3 (JEDEC MS-013-AE ISSUE C)**  
28 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.0926	0.1043	2.35	2.65	-
A1	0.0040	0.0118	0.10	0.30	-
B	0.013	0.0200	0.33	0.51	9
C	0.0091	0.0125	0.23	0.32	-
D	0.6969	0.7125	17.70	18.10	3
E	0.2914	0.2992	7.40	7.60	4
e	0.05 BSC		1.27 BSC		-
H	0.394	0.419	10.00	10.65	-
h	0.01	0.029	0.25	0.75	5
L	0.016	0.050	0.40	1.27	6
N	28		28		7
$\alpha$	$0^\circ$	$8^\circ$	$0^\circ$	$8^\circ$	-

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